

TOSHIBA TRANSISTOR SILICON NPN EPITAXIAL TYPE (PCT PROCESS)

2SC1627A

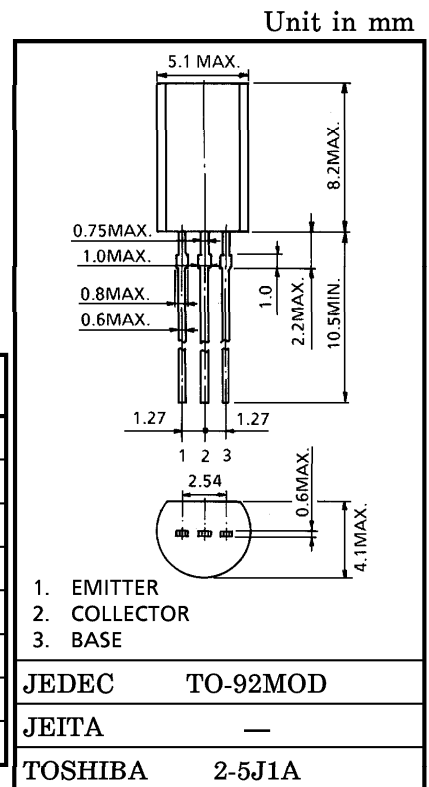
DRIVER STAGE AMPLIFIER APPLICATIONS

VOLTAGE AMPLIFIER APPLICATIONS

- Complementary to 2SA817A.
- Driver Stage Application of 30 to 35 Watts Amplifiers.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V _{CB0}	80	V
Collector-Emitter Voltage	V _{CEO}	80	V
Emitter-Base Voltage	V _{EBO}	5	V
Collector Current	I _C	400	mA
Base Current	I _B	40	mA
Collector Power Dissipation	P _C	800	mW
Junction Temperature	T _j	150	°C
Storage Temperature Range	T _{stg}	-55~150	°C

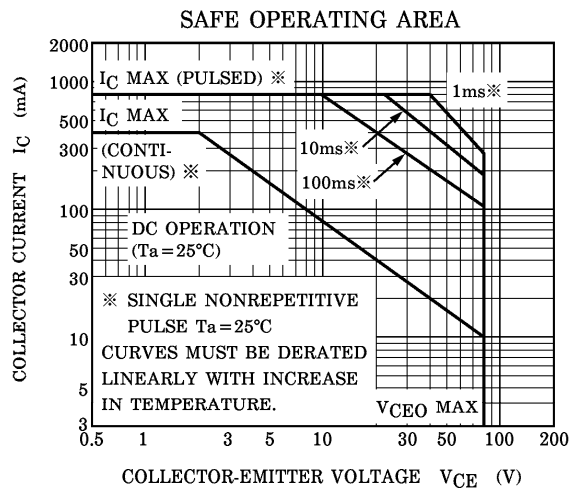
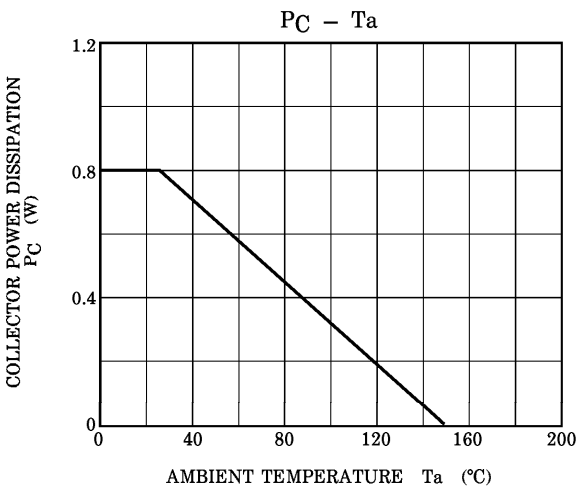
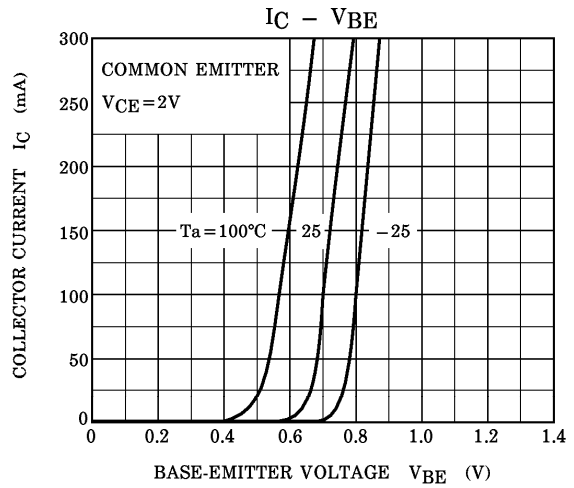
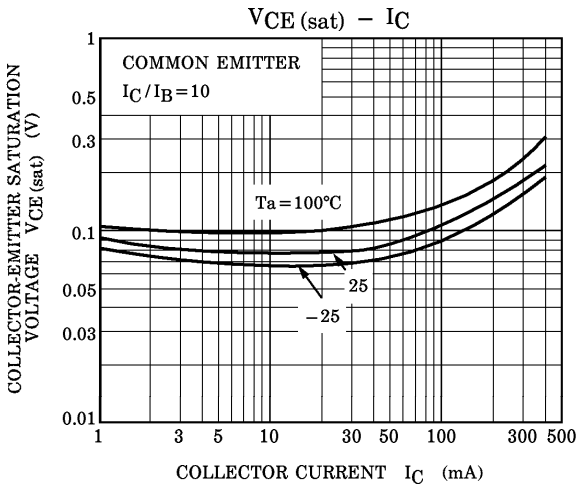
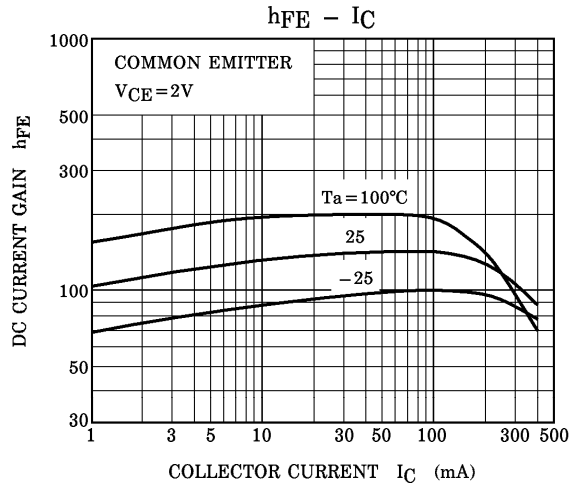
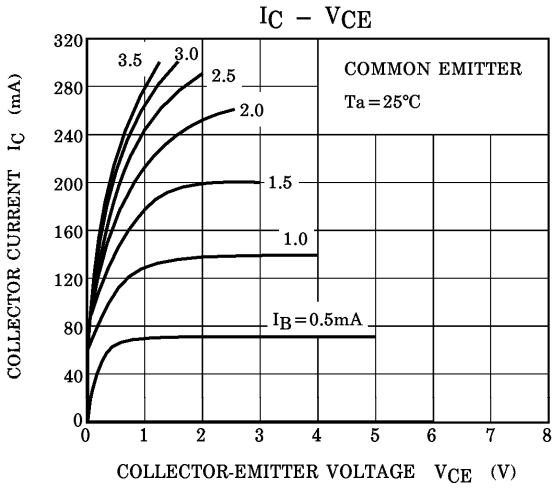


Weight : 0.36g (Typ.)

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	I _{CBO}	V _{CB} = 50V, I _E = 0	—	—	100	nA
Emitter Cut-off Current	I _{EBO}	V _{EB} = 5V, I _C = 0	—	—	100	nA
Collector-Emitter Breakdown Voltage	V _{(BR) CEO}	I _C = 5mA, I _B = 0	80	—	—	V
DC Current Gain	h _{FE} (1) (Note)	V _{CE} = 2V, I _C = 50mA	70	—	240	
	h _{FE} (2)	V _{CE} = 2V, I _C = 200mA	40	—	—	
Collector-Emitter Saturation Voltage	V _{CE (sat)}	I _C = 200mA, I _B = 20mA	—	—	0.4	V
Base-Emitter Voltage	V _{BE}	V _{CE} = 2V, I _C = 5mA	0.55	—	0.8	V
Transition Frequency	f _T	V _{CE} = 10V, I _C = 10mA	—	100	—	MHz
Collector Output Capacitance	C _{ob}	V _{CB} = 10V, f = 1MHz	—	10	—	pF

(Note) : h_{FE} (1) Classification O : 70~140, Y : 120~240



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